

PRM021N06S8

PFC Device Corporation

60V Single N-Channel MOSFET

Major ratings and characteristics

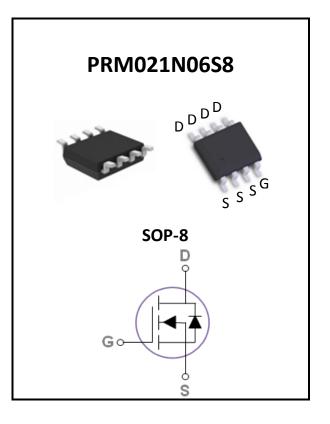
Characteristics	Values	Units
V _{DS}	60	V
I _D (T _A =25°C)	7.7	Α
Max. R _{DS(ON)}	21.0	mΩ
T _J Operating Junction Temperature	-55 to +150	°C

General Description

The N-Channel enhancement mode power field effect transistor is using trench DMOS technology. This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. The device is well suited for high efficiency fast switching applications.

Typical Applications

- Charger Adapter
- Power Tools
- LED Lighting



Features

- Max. $R_{DS(ON)}=21m\Omega@V_{GS}=10V$
- Improved dv/dt capability
- Fast switching
- 100% E_{AS} Guaranteed
- Green Device Available

1. Characteristics

Maximum Ratings Characteristics

($T_A = 25$ °C unless otherwise specified)

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	60	V
V _{GS}	Gate-Source Voltage	±20	V
1	Drain Current – Continuous ($T_A=25^{\circ}C$)	7.7	А
Ι _D	Drain Current – Continuous (T _A =100°C)	4.8	А
I _{DM}	Drain Current – Pulsed ¹	32	А
E _{AS}	Single Pulse Avalanche Energy ²	12	mJ
I _{AS}	Single Pulse Avalanche Current ²	16	А
Р	Power Dissipation (T _A =25°C)	2.5	W
P _D	Power Dissipation – Derate above 25°C	0.02	W/°C
T _{STG}	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
R _{θJA}	Thermal Resistance Junction to Ambient		50	°C/W



Electrical Characteristics

 $(T_J = 25 °C unless otherwise specified)$

Off Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV_{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250uA	60			V
	Drain Source Leekage Current	V _{DS} =60V, V _{GS} =0V, T _J =25°C			1	uA
IDSS	Drain-Source Leakage Current	V _{DS} =60V, V _{GS} =0V, T _J =125°C			250	uA
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V, V _{DS} =0V			±100	nA

On Characteristics

R _{DS(ON)} Static Drain-Source On-Resistance	V _{GS} =10V, I _D =3A		17	21	mΩ	
$R_{DS(ON)}$		V _{GS} =4.5V, I _D =2A		20	24	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =250uA	1.0	1.8	3.0	V
g _{fs}	Forward Transconductance	V _{DS} =10V, I _D =3A		17		S

Dynamic and switching Characteristics

Q _g	Total Gate Charge ^{3, 4}	V _{DS} =30V, V _{GS} =10V, I _D =7.7A	 21	
Q _{gs}	Gate-Source Charge ^{3,4}		 3.8	 nC
Q_gd	Gate-Drain Charge ^{3,4}		 4.0	
T _{d(on)}	Turn-On Delay Time ^{3, 4}		 9	
T _r	Turn-On Rise Time ^{3, 4}	V_{DD} =30V, V_{GS} =10V, R_G =6 Ω I_D =7.7A	 42	 200
T _{d(off)}	Turn-Off Delay Time ^{3, 4}		 26	 ns
T _f	Turn-Off Fall Time ^{3, 4}		 41	
C _{iss}	Input Capacitance		 1200	
C _{oss}	Output Capacitance	V_{DS} =25V, V_{GS} =0V, f=1MHz	 100	 pF
C _{rss}	Reverse Transfer Capacitance		 65	
R _g	Gate resistance	V _{GS} =0V, V _{DS} =0V, f=1MHz	 2.8	 Ω

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Voltage	V _{GS} =0V, I _S =7.7A	 	1.5	V
t _{rr}	Reverse Recovery Time	I _7.7.4 di/dt_100.0 /u.e	 15		ns
Q _{rr}	Reverse Recovery Charge	I _S =7.7A, di/dt=100A/us	 3.5		nC

Note :

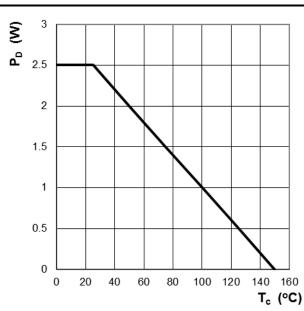
1. Repetitive Rating : Pulsed width limited by maximum junction temperature.

2. V_{DD} =50V, V_{GS} =10V, L=0.1mH, I_{AS}=16A, R_G=25\Omega, Starting T_J=25°C

3. The data tested by pulsed, pulse width \leq 300us, duty cycle \leq 2%.

4. Essentially independent of operating temperature.

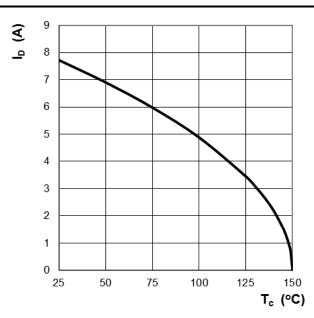




Ratings and Characteristics Curves

2. Characteristics Curves





($T_A = 25^{\circ}C$ unless otherwise specified)

Figure 2: Continuous Drain Current vs. Tc

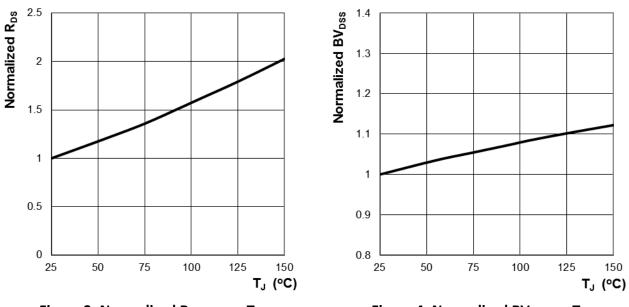


Figure 3: Normalized R_{DS(ON)} vs. T_J





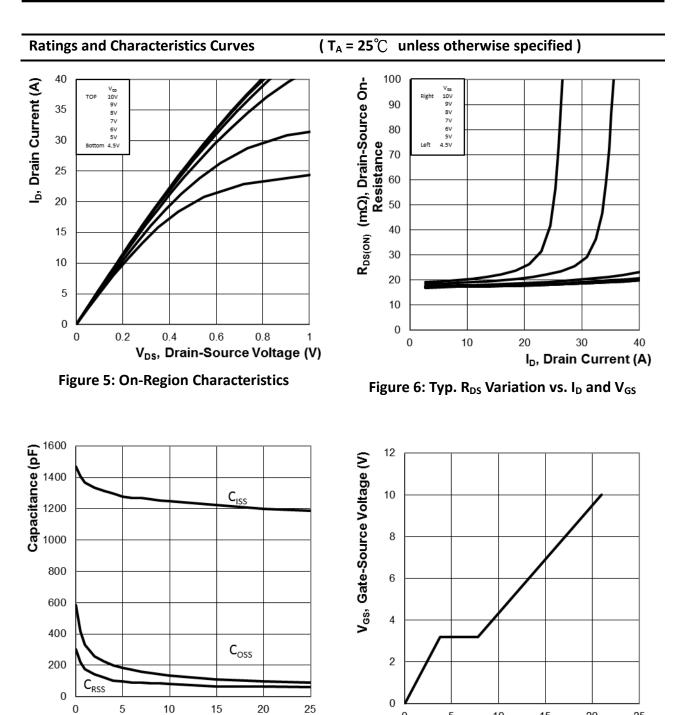


Figure 7: Typ. Capacitance Characteristics

V_{DS}, Drain to Source Voltage (V)



10

15

Q_G, Total Gate Charge (nC)

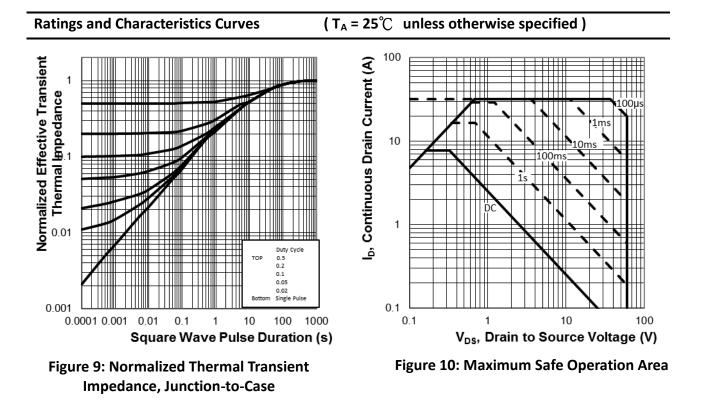
20

25

5

0

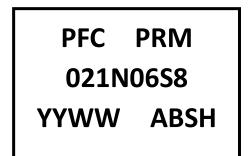






3. Marking information

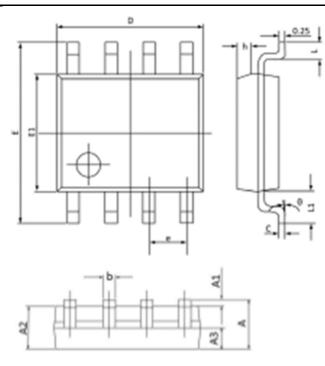
Top Marking Rule



PRM021N06S8 = Product Type Marking Code YYWW = Date Code YY = Last two digits of year WW = Week code ABS = Assembly code H = Halogen Free (N/A = common molding compound)

4. Package information

Package Outline Dimensions millimeters



Dim.	Min.	Max.		
Α	1.35	1.75		
Al	0.10	0.25		
A2	1.30			
A3	0.60	0.70		
b	0.35	0.49		
С	0.18	0.26		
D	4.70	5.10		
E	5.80	6.20		
El	3.70	4.10		
е	1.27	BSC		
h	0.25	0.50		
L	0.40	0.90		
Ll	1.05 BSC			
θ	0°	8°		
All Dimensions in mm				



5. Ordering information

Part Number	Package	Delivery mode
PRM021N06S8	SOP-8	3000 pcs / 13" diameter reel

Mechanical

- Molder Plastic: UL Flammability Classification Rating 94V-0
- Device Weight: 0.003 ounces (0.085grams) SOP-8

PFC Device Corp reserves the right to make changes without further notice to any products herein. PFC Device Corp makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does PFC Device Corp assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in PFC Device Corp data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typical" must be validated for each customer application by customer's technical experts. PFC Device Corp does not convey any license under its patent rights nor the rights of others. PFC Device Corp products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the PFC Device Corp product could create a situation where personal injury or death may occur. Should Buyer purchase or use PFC Device Corp products for any such unintended or unauthorized application, Buyer shall indemnify and hold PFC Device Corp and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that PFC Device Corp was negligent regarding the design or manufacture of the part.

